TLE7270-2

5-V Low Dropout Voltage Regulator

Automotive Power



Never stop thinking



5-V Low Dropout Voltage Regulator

TLE7270-2



1 Overview

Features

- Ultra Low Current Consumption 20 μA
- Output Voltage 5 V ±2%
- Output Current up to 300 mA
- Power-On and Undervoltage Reset
- Reset Low Down to V_Q = 1 V
- Very Low Dropout Voltage
- Output Current Limitation
- Overtemperature Shutdown
- Wide Temperature Range From -40 °C up to 150 °C
- Green Product (RoHS compliant)
- AEC Qualified

Description

The TLE7270-2 is a monolithic integrated low dropout voltage regulator for load currents up to 300 mA. An input voltage up to 42 V is regulated to $V_{Q,nom} = 5.0$ V with a precision of $\pm 2\%$. Due to its integrated reset circuitry featuring power on timing and output voltage monitoring the IC is well suited as μ -controller supply. The sophisticated design allows to achieve stable operation even with ceramic output capacitors down to 470 nF. The device is designed for the harsh environment of automotive applications. Therefore it is protected against overload, short circuit and overtemperature conditions by the implemented output current limitation and the overtemperature shutdown circuit. The TLE7270-2 can be also used in all other applications requiring a stabilized 5 V voltage.

Due to its ultra low quiescent current of typically 20 μ A the TLE7270-2 is dedicated for use in applications permanently connected to V_{BAT} . An integrated output sink current circuitry keeps the voltage at the Output pin Q below 5.5 V even in case of occuring reverse currents. Thus connected devices are protected from overvoltage damage. For applications requiring extremely low noise levels the Infineon voltage regulator family TLE 42XX and TLE 44XX is more suited than the TLE7270-2. A mV-range output noise on the TLE7270-2 caused by the charge pump operation is unavoidable due to the ultra low quiescent current concept.



| Туре | Package | Marking |
|------------|------------------------|---------|
| TLE7270-2E | PG-SSOP-14 Exposed Pad | 7270-2E |
| TLE7270-2D | PG-TO252-5 | 7270-2D |
| TLE7270-2G | PG-TO263-5 | 7270-2G |



Block Diagram

2 Block Diagram

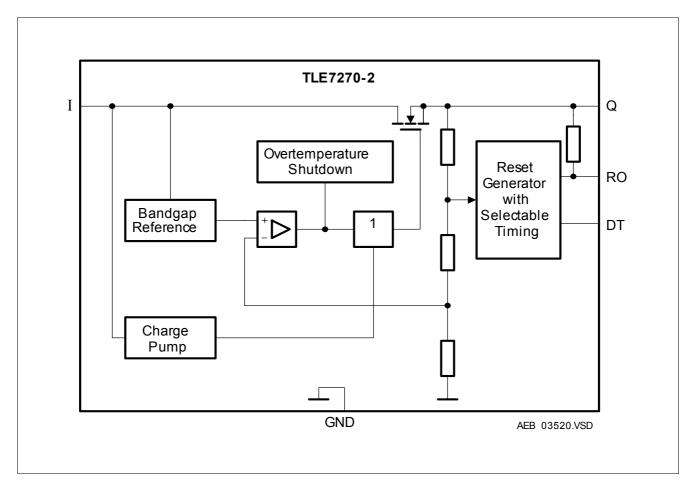


Figure 1 Block Diagram



Pin Configuration

3 Pin Configuration

3.1 Pin Assignment PG-SSOP-14 Exposed Pad

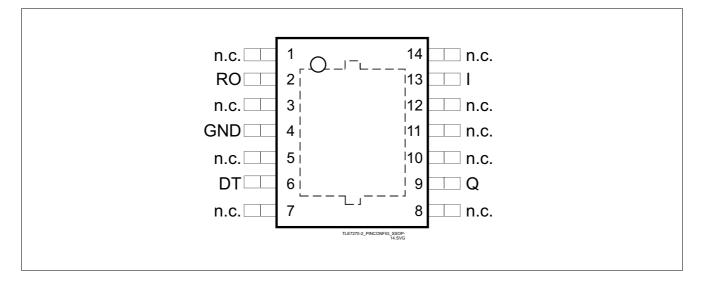


Figure 2 Pin Configuration (top view)

3.2 Pin Definitions and Functions PG-SSOP-14 Exposed Pad

| Pin No. | Symbol | Function |
|---------------|--------|---|
| 1,3,5,7 | n.c. | non connected |
| | | can be open or connected to GND |
| 2 | RO | Reset Output |
| | | open collector output with integrated pull-up resistor; |
| | | optional external pull-up resistor of \geq 10 k Ω to pin Q; |
| | | leave open if reset function not needed |
| 4 | GND | Ground |
| 6 | DT | Delay Timing |
| | | connect to GND or Q to choose the Power On Reset Delay Time |
| 8,10,11,12,14 | n.c. | non connected |
| | | can be open or connected to GND |
| 9 | Q | Output |
| | | block to ground with a capacitor close to the IC terminals, respecting the values given |
| | | for its capacitance and ESR in "Functional Range" on Page 6 |
| 13 | 1 | Input |
| | | block to ground directly at the IC with a ceramic capacitor |
| Pad | - | Exposed Pad |
| | | connect to GND and heatsink area |



Pin Configuration

3.3 Pin Assignment PG-TO252-5, PG-TO263-5

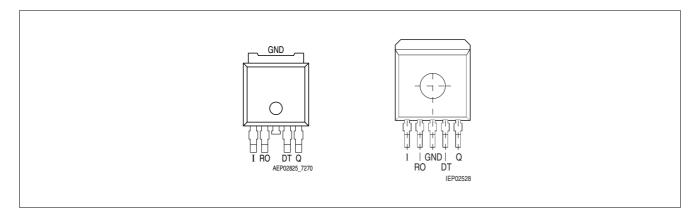


Figure 3 Pin Configuration (top view)

3.4 Pin Definitions and Functions PG-TO252-5, PG-TO263-5

| Pin No. | Symbol | Function |
|-----------|--------|---|
| 1 | 1 | Input |
| | | block to ground directly at the IC with a ceramic capacitor |
| 2 | RO | Reset Output |
| | | open collector output with integrated pull-up resistor; |
| | | optional external pull-up resistor of \geq 10 k Ω to pin Q; |
| | | leave open if reset function not needed |
| 3 | GND | Ground |
| | | internally connected to heat slug |
| 4 | DT | Delay Timing |
| | | connect to GND or Q to choose the Power On Reset Delay Time |
| 5 | Q | Output |
| | | block to ground with a capacitor close to the IC terminals, respecting the values given |
| | | for its capacitance and ESR in "Functional Range" on Page 6 |
| Heat Slug | _ | Heat Slug |
| | | internally connected to GND; |
| | | connect to GND and heatsink area |



4 General Product Characteristics

4.1 Absolute Maximum Ratings

Absolute Maximum Ratings¹⁾

T_i = -40 °C to 150 °C; all voltages with respect to ground, (unless otherwise specified)

| Pos. | Parameter | Symbol | Lin | nit Values | Unit | Test Condition |
|---------|--|-------------------------------------|------|------------|------|-------------------------|
| | | | Min. | Max. | | |
| Input I | | 4 | L | H | | |
| 4.1.1 | Voltage | $V_{\rm I}$ | -0.3 | 45 | V | - |
| Output | Q, Reset Output RO, Delay Time | DT | | | I | |
| 4.1.2 | Voltage | $V_{ m Q}, V_{ m RO}, V_{ m DT}$ | -0.3 | 6 | V | - |
| 4.1.3 | Voltage | $V_{\rm Q}, V_{\rm RO}, V_{\rm DT}$ | -0.3 | 6.2 | V | $t < 10 \text{ s}^{2)}$ |
| Tempe | rature | | | | | |
| 4.1.4 | Junction temperature | $T_{\rm i}$ | -40 | 150 | °C | - |
| 4.1.5 | Storage temperature | T _{stg} | -50 | 150 | °C | - |
| ESD Si | usceptibility | | | H | | |
| 4.1.6 | Human Body Model (HBM) ³⁾ | Voltage | - | 3 | kV | - |
| 4.1.7 | Charged Device Model (CDM) ⁴⁾ | Voltage | - | 1.5 | kV | - |
| 4 | · | | 1 | 1 | 1 | 1 |

1) not subject to production test, specified by design

2) exposure to these absolute maximum ratings for extended periods (t > 10 s) may affect device reliability

3) ESD susceptibility Human Body Model "HBM" according to AEC-Q100-002 - JESD22-A114

4) ESD susceptibility Charged Device Model "CDM" according to ESDA STM5.3.1

Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

4.2 Functional Range

| Pos. | Parameter | Symbol | Limit Values | | | Remarks |
|-------|----------------------|------------|--------------|-----|----|---------|
| | | Min. | Max. | | | |
| 4.2.1 | Input voltage | V | 5.5 | 42 | V | - |
| 4.2.2 | Output Capacitor's | CQ | 470 | - | nF | 1) |
| 4.2.3 | Requirements | $ESR(C_Q)$ | - | 10 | Ω | 2) |
| 4.2.4 | Junction temperature | Tj | -40 | 150 | °C | - |

1) the minimum output capacitance requirement is applicable for a worst case capacitance tolerance of 30%

2) relevant ESR value at f = 10 kHz

Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.



General Product Characteristics

4.3 Thermal Resistance

Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to www.jedec.org.

| Pos. | Parameter | Symbol | | Limit Val | ues | Unit | Conditions |
|-------|-----------------------------------|---------------------|------|-----------|----------|------|--|
| | | | Min. | Тур. | Max. | | |
| TLE72 | 70-2E (PG-SSOP-14 Exposed | Pad) | | | | | I |
| 4.3.1 | Junction to Case ¹⁾ | R _{thJC} | - | 14 | - | K/W | measured to exposed pad |
| 4.3.2 | Junction to Ambient ¹⁾ | R _{thJA} | _ | 47 | _ | K/W | 2) |
| 4.3.3 | | R _{thJA} | - | 141 | _ | K/W | footprint only ³⁾ |
| 4.3.4 | | R _{thJA} | - | 66 | - | K/W | 300 mm ² heatsink area ³⁾ |
| 4.3.5 | _ | R _{thJA} | - | 56 | - | K/W | 600 mm ² heatsink area ³⁾ |
| TLE72 | 70-2D (PG-TO252-5) | | - | | I | | |
| 4.3.1 | Junction to Case ¹⁾ | R _{thJC} | - | 6 | - | K/W | measured to tab |
| 4.3.2 | Junction to Ambient ¹⁾ | R _{thJA} | - | 32 | - | K/W | 2) |
| 4.3.3 | | R_{thJA} | - | 115 | - | K/W | footprint only ³⁾ |
| 4.3.4 | | R_{thJA} | - | 62 | - | K/W | 300 mm ² heatsink area ³⁾ |
| 4.3.5 | | R _{thJA} | - | 47 | - | K/W | 600 mm ² heatsink area ³⁾ |
| TLE72 | 70-2G (PG-TO263-5) | | | | | | IL |
| 4.3.1 | Junction to Case ¹⁾ | R _{thJC} | - | 6 | - | K/W | measured to exposed pad |
| 4.3.2 | Junction to Ambient ¹⁾ | R _{thJA} | _ | 27 | - | K/W | 2) |
| 4.3.3 | | R _{thJA} | - | 75 | - | K/W | footprint only ³⁾ |
| 4.3.4 | | R _{thJA} | - | 47 | - | K/W | 300 mm ² heatsink area ³⁾ |
| 4.3.5 | | R _{thJA} | - | 38 | - | K/W | 600 mm ² heatsink area ³⁾ |

1) Not subject to production test, specified by design.

 Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm³ board with 2 inner copper layers (2 x 70µm Cu, 2 x 35µm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

3) Specified R_{thJA} value is according to Jedec JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 × 114.3 × 1.5 mm³ board with 1 copper layer (1 x 70µm Cu).



5 Electrical Characteristics

5.1 Electrical Characteristics Voltage Regulator

Electrical Characteristics

| V_1 =13.5 V; T_j = -40 °C to 150 °C; all voltage | es with respect | t to ground (unle | ss otherwi | ise specified) |
|--|-----------------|-------------------|------------|----------------|
| | | | | |

| | , | - | | | | | | |
|--------|--|----------------------------|--------------|---------|-------|--|---|--|
| Pos. | Parameter | Symbol | Limit Values | | | Unit | Measuring Condition | |
| | | | Min. | Тур. | Max. | | | |
| Output | t Q | - | 1 | | | | | |
| 5.1.1 | Output Voltage | V _Q 4.9 5.0 5.1 | | 5.0 5.1 | 5.1 V | 0.1 mA < I_Q <300 mA 6 V < V_I < 16 V | | |
| 5.1.2 | Output Voltage | V _Q | 4.9 | 5.0 | 5.1 | V | 0.1 mA < I_Q <100 mA 6 V < V_I < 40 V | |
| 5.1.3 | Dropout Voltage | V _{dr} | - | 250 | 500 | mV | $I_{\rm Q}$ = 200 mA $V_{\rm dr}$ = $V_{\rm I} - V_{\rm Q}^{1)}$ | |
| 5.1.4 | Load Regulation | $\Delta V_{Q, lo}$ | - 40 | 15 | 40 | mV | I_Q = 5 mA to 250 mA | |
| 5.1.5 | Line Regulation | $\Delta V_{ m Q, li}$ | - 20 | 5 | 20 | mV | $V_1 = 10 \text{ V to } 32 \text{ V}$ $I_Q = 5 \text{ mA}$ | |
| 5.1.6 | Output Current Limitation | IQ | 301 | - | - | mA | 1) | |
| 5.1.7 | Output Current Limitation | IQ | - | - | 800 | mA | $V_{\rm Q} = 0 V$ | |
| 5.1.8 | Power Supply Ripple Rejection ²⁾ | PSRR | - | 60 | - | dB | <i>f</i> _r = 100 Hz; <i>V</i> _r = 0.5 Vpp | |
| 5.1.9 | Temperature Output Voltage Drift | $\frac{dV_{Q}}{dT}$ | - | 0.5 | - | mV/K | - | |
| Curren | t Consumption | - | 1 | | | | | |
| 5.1.10 | Quiescent Current $I_q = I_1 - I_Q$ | Iq | _ | 20 | 30 | μA | $I_{Q} = 0.1 \text{ mA}$ $T_{j} = 25 \text{ °C}$ | |
| 5.1.11 | Quiescent Current $I_{q} = I_{l} - I_{Q}$ | Iq | - | - | 40 | μA | $I_{\rm Q}$ = 0.1 mA $T_{\rm i} \le 80 \ ^{\circ}{\rm C}$ | |

 $\frac{|I_q = I_1 - I_Q|}{|I_q = I_1 - I_Q|} \frac{|I_q = I_1 - I_Q|}{|I_q = I_1 - I_Q|} \frac{|I_q = I_1 - I_Q|}{|I_q = I_1 - I_Q|}$

2) not subject to production test, specified by design

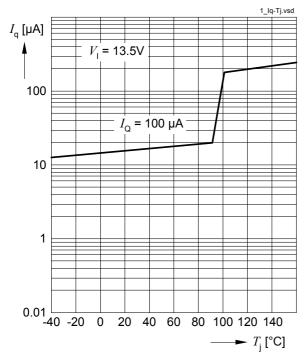
TLE7270-2

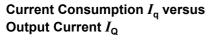


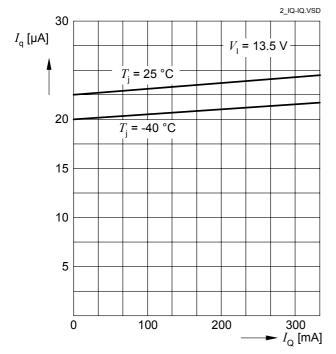
Electrical Characteristics

5.2 Typical Performance Characteristics Voltage Regulator

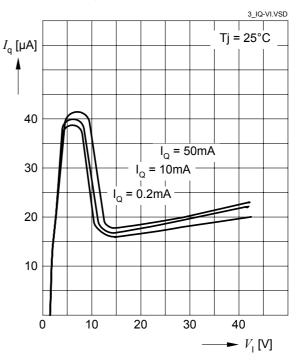
Current Consumption $I_{\rm q}$ versus Junction Temperature $T_{\rm J}$



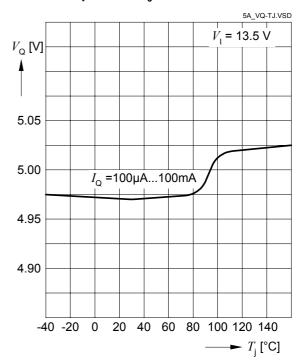




Current Consumption $I_{\rm q}$ versus Input Voltage $V_{\rm IQ}$



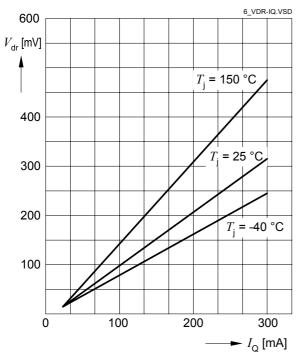
Output Voltage V_{Q} versus Junction Temperature T_{J}



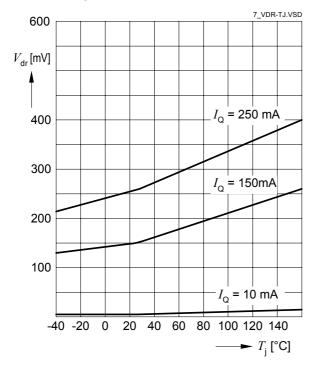


Electrical Characteristics

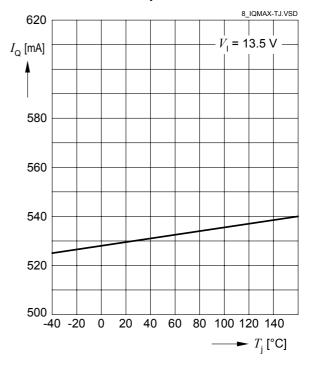
Dropout Voltage $V_{\rm dr}$ versus Output Current $I_{\rm Q}$



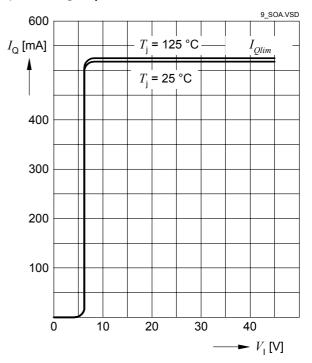
Dropout Voltage $V_{\rm dr}$ versus Junction Temperature



Maximum Output Current I_{Q} versus Junction Temperature T_{j}



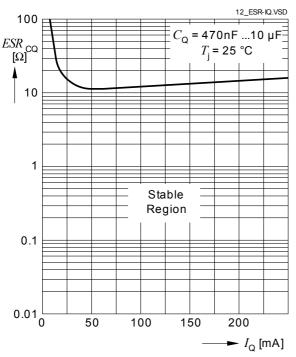
Maximum Output Current I_{Q} versus Input Voltage V_{I}



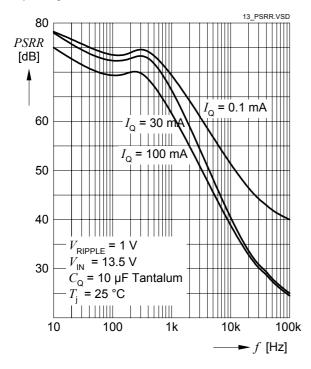




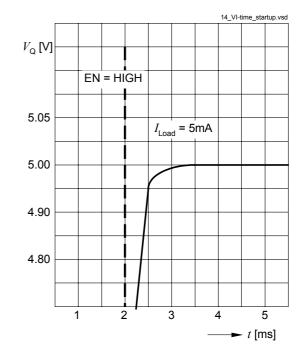
Region of Stability



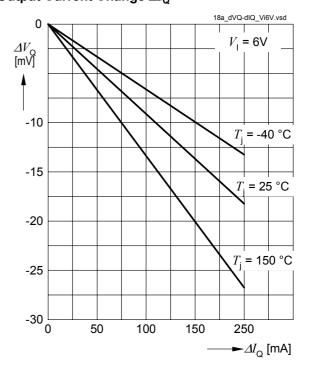
Power Supply Ripple Rejection PSRR versus Frequency f



Output Voltage V_{Q} Start-up behavior

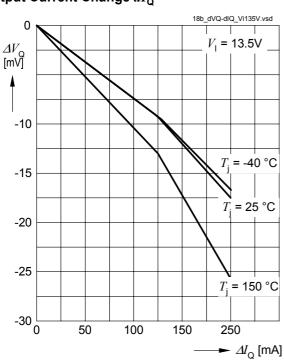


Load Regulation ΔV_{Q} versus Output Current Change ΔI_{Q}



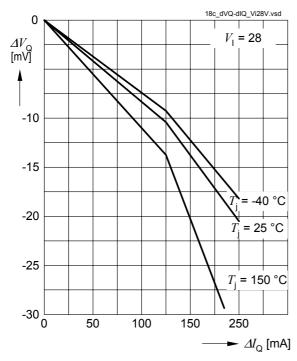


Electrical Characteristics

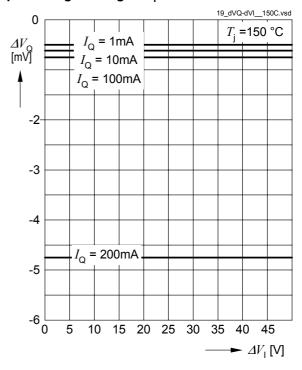


Load Regulation ΔV_{Q} versus Output Current Change dI_{Q}

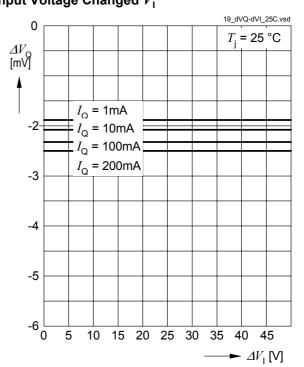
Load Regulation ΔV_{Q} versus Output Current Change ΔI_{Q}





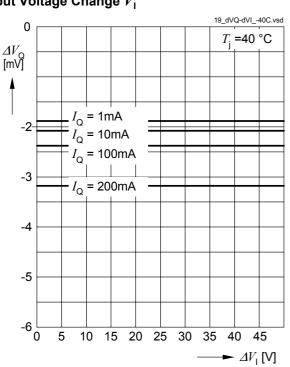


Line Regulation ΔV_{Q} versus Input Voltage Changed V_{I}



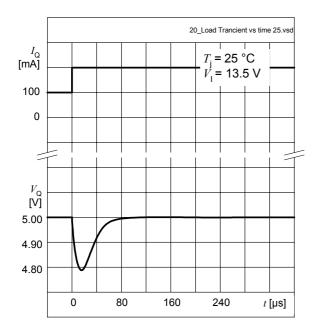


Electrical Characteristics

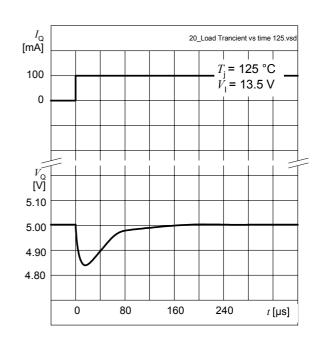


Line Regulation ΔV_{Q} versus Input Voltage Change V_{I}

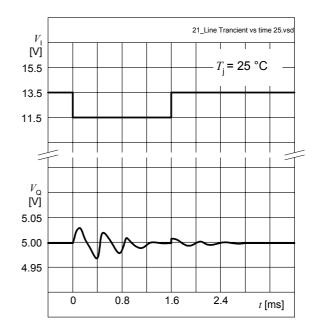
Load Transient Response Peak Voltage ΔV_{Q}



Load Transient Response Peak Voltage $\Delta V_{\rm Q}$



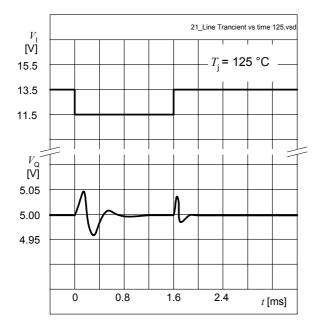
Line Transient Response Peak Voltage $\Delta V_{\rm Q}$





ı

Electrical Characteristics



Line Transient Response Peak Voltage $\Delta V_{ m Q}$

5.3 Electrical Characteristics Reset Function

The Reset function informs e.g. the microcontroller in case the output voltage has fallen below the lower threshold **VRT** of typ. 4.65 V. The headroom **VRH** between the output voltage and the reset threshold is typically 350 mV. Connecting the regulator to a battery voltage at first the reset signal remains LOW. When the output voltage has reached the reset threshold **VRT** the reset output RO remains still LOW for the reset delay time **tRD**. Afterwards the reset output turns HIGH.

| Pos. | Parameter | Symbol | Limit | Values | | Unit | Conditions |
|-------|--|---------------------|-------|--------|------|------|--|
| | | | Min. | Тур. | Max. | _ | |
| 5.3.1 | Output Undervoltage Reset Switching Threshold | V _{RT} | 4.50 | 4.65 | 4.80 | V | $V_{\rm Q}$ decreasing $V_{\rm I}$ = 6V |
| 5.3.2 | Output Undervoltage Reset Headroom | V _{RH} | - | 350 | - | mV | - |
| 5.3.3 | Reset Output Low Level Voltage | V _{ROL} | - | 0.2 | 0.4 | V | $R_{ m RO}$ = 10 kΩ; $V_{ m Q}$ > 1 V |
| 5.3.4 | Integrated Reset Pull Up Resistor | R _{RO} | 15 | 30 | 45 | kΩ | - |
| 5.3.5 | Optional External Reset Pull Up Resistor | R _{RO,ext} | 10 | - | - | kΩ | - |
| 5.3.6 | Power On Reset Delay Time | t _{RD} | 10 | 16 | 22 | ms | pin DT connected to GND |
| 5.3.7 | Power On Reset Delay Time | t _{RD} | 80 | 128 | 176 | ms | pin DT connected to Q |
| 5.3.8 | Reset Reaction Time | t _{RR} | _ | - | 12 | μs | _ |

Electrical Characteristics Reset

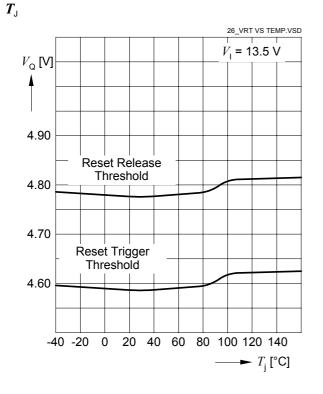
 V_1 =13.5 V; – 40 °C < T_1 < 150 °C; all voltages with respect to ground (unless otherwise specified)

TLE7270-2

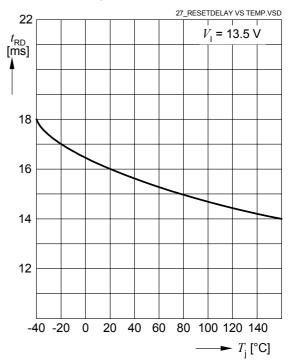


Electrical Characteristics

5.4 Typical Performance Characteristics Reset Function



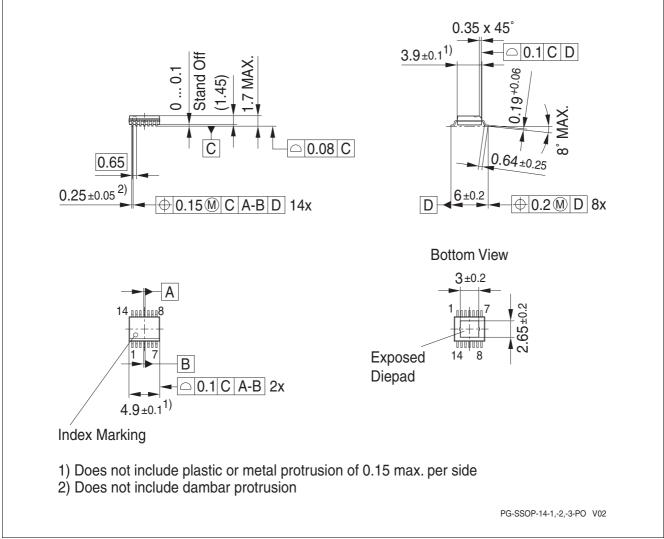
Reset Threshold $V_{\rm RT}$ versus Junction TemperatureReset Delay $t_{\rm RD}$ versus $T_{\rm J}$ Junction Temperature $T_{\rm J}$ at fast timing (DT26 VRT VS TEMP.VSDconnected to GND)





Package Outlines

6 Package Outlines







TLE7270-2

Package Outlines

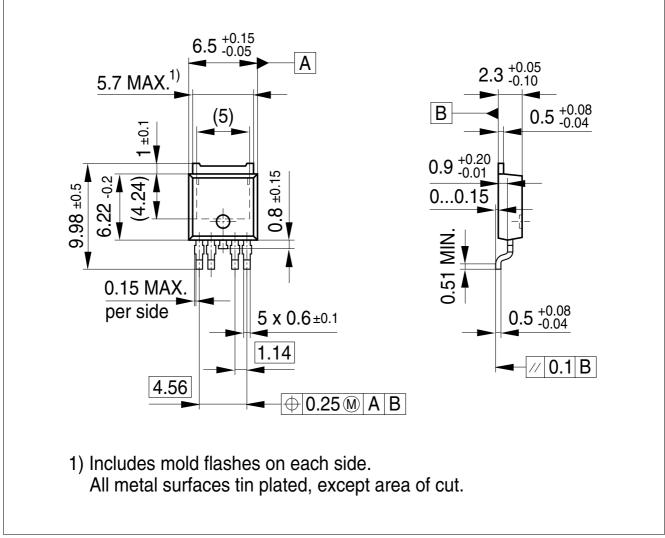


Figure 5 PG-TO252-5





Package Outlines

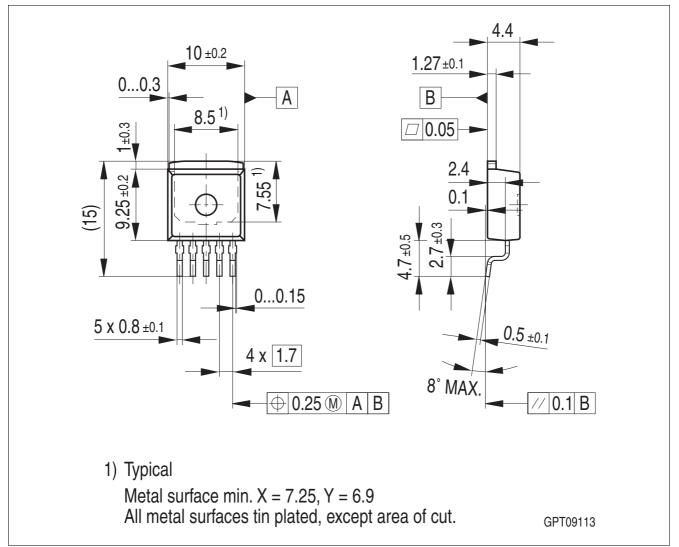


Figure 6 PG-TO263-5

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

For further information on alternative packages, please visit our website: http://www.infineon.com/packages.



Revision History

7 Revision History

| Revision | Date | Changes |
|----------|------------|---|
| 1.01 | 2009-07-23 | updated version data sheet: |
| | | in "Electrical Characteristics Voltage Regulator" on Page 8 , former Item 5.1.12 "Current Consumption, Regulator Disabled" removed, in Condition of Item 5.1.10 and Item 5.1.11 " V_{EN} = 5 V" removed: Non relevant information as TLE7270-2 does not implement Enable Feature |
| 1.0 | 2009-06-01 | initial version data sheet |

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